

Discrete POWER & Signal **Technologies**

PN3638 PN3638A



PNP General Purpose Amplifier

This device is designed for use as general purpose amplifiers and switches requiring collector currents to 500 mA. Sourced from Process 63. See PN2907A for characteristics.

Absolute Maximum Ratings*

TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V_{CEO}	Collector-Emitter Voltage	25	V
V _{CBO}	Collector-Base Voltage	25	V
V _{EBO}	Emitter-Base Voltage	4.9	V
lc	Collector Current - Continuous	800	mA
T _J , T _{stg}	Operating and Storage Junction Temperature Range	-55 to +150	°C

^{*}These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

1) These ratings are based on a maximum junction temperature of 150 degrees C.

2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Thermal Characteristics

TA = 25°C unless otherwise noted

Symbol	Characteristic	Max	Units
		PN3638/A	
P _D	Total Device Dissipation	625	mW
	Derate above 25°C	5.0	mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	°C/W

PNP General Purpose Amplifier (continued)

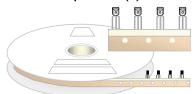
Symbol	Parameter	Test Conditions	Min	Max	Units
OFF CHA	RACTERISTICS				
V _{(BR)CEO}	Collector-Emitter Breakdown	$I_C = 10 \text{ mA}, I_B = 0$	25		V
V _{(BR)CES}	Voltage* Collector-Emitter Breakdown	I _C = 100 μA, I _B = 0	25		V
V _(BR) CBO	Voltage* Collector-Base Breakdown Voltage	$I_{C} = 10 \mu A, I_{E} = 0$	25		V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	$I_C = 10 \mu A, I_C = 0$ $I_E = 10 \mu A, I_C = 0$	4.0		V
ICES	Collector-Cutoff Current	V _{CE} = 15 V, I _E = 0	1.0	35	nA
		$V_{CE} = 15 \text{ V}, I_{E} = 0, T_{A} = 65^{\circ}\text{C}$		2.0	μA
ON CHAR	RACTERISTICS*				
h _{FE}	DC Current Gain	$V_{CE} = 1.0 \text{ V}, I_{C} = 50 \text{ mA}$			
		PN3638 PN3638A	30 100		
		$V_{CE} = 2.0 \text{ V}, I_{C} = 300 \text{ mA}$	100		
		PN3638	30		
		PN3638A V _{CE} = 10 V, I _C = 100 mA	20		
		PN3638	20		
		PN3638A	80		
		V _{CE} = 10 V, I _C = 1.0 mA PN3638A	100		
V _{CE(sat)}	Collector-Emitter Saturation Voltage	$I_C = 50 \text{ mA}, I_B = 2.5 \text{ mA}$ $I_C = 300 \text{ mA}, I_B = 30 \text{ mA}$		0.25 1.0	V
V _{BE(sat)}	Base-Emitter Saturation Voltage	$I_C = 50 \text{ mA}, I_B = 2.5 \text{ mA}$		1.1	V
V _{BE(sat)}	Base-Emitter Saturation Voltage		0.8		
V _{BE(sat)}	Base-Emitter Saturation Voltage IGNAL CHARACTERISTICS	$I_C = 50 \text{ mA}, I_B = 2.5 \text{ mA}$	0.8	1.1	V
	-	$\begin{split} & \text{Ic} = 50 \text{ mA, I}_{\text{B}} = 2.5 \text{ mA} \\ & \text{Ic} = 300 \text{ mA, I}_{\text{B}} = 30 \text{ mA} \end{split}$ $& \text{V}_{\text{CB}} = 10 \text{ V, f} = 1.0 \text{ MHz}$	0.8	1.1 2.0	V
SMALL S	IGNAL CHARACTERISTICS	$\begin{tabular}{lc} I_C = 50 & mA, \ I_B = 2.5 & mA \\ I_C = 300 & mA, \ I_B = 30 & mA \end{tabular}$ $\begin{tabular}{lc} V_{CB} = 10 & V, \ f = 1.0 & MHz \\ \hline \end{tabular}$	0.8	1.1 2.0	V V
SMALL S	IGNAL CHARACTERISTICS Output Capacitance	$\begin{tabular}{lc} I_C = 50 & mA, \ I_B = 2.5 & mA \\ I_C = 300 & mA, \ I_B = 30 & mA \end{tabular}$ $\begin{tabular}{lc} $V_{CB} = 10 & V, \ f = 1.0 & MHz \\ \hline PN3638 \\ PN3638A \end{tabular}$	0.8	1.1 2.0	V
SMALL S	IGNAL CHARACTERISTICS	$\begin{tabular}{lccccc} Ic = 50 & mA, I_B = 2.5 & mA \\ I_C = 300 & mA, I_B = 30 & mA \end{tabular}$ $\begin{tabular}{lcccc} $V_{CB} = 10 & V, f = 1.0 & MHz \\ P N3638 \\ P N3638A \end{tabular}$ $\begin{tabular}{lcccc} $V_{BE} = 0.5 & V, f = 1.0 & MHz \\ P N3638 \end{tabular}$	0.8	1.1 2.0 20 10 65	V V PF pF
SMALL S C _{ob}	IGNAL CHARACTERISTICS Output Capacitance Input Capacitance	$\label{eq:controller} \begin{array}{c} I_{C} = 50 \text{ mA}, \ I_{B} = 2.5 \text{ mA} \\ I_{C} = 300 \text{ mA}, \ I_{B} = 30 \text{ mA} \\ \\ \hline \\ V_{CB} = 10 \text{ V}, \ f = 1.0 \text{ MHz} \\ \hline \\ PN3638 \\ \hline \\ \\ PN3638 \\ \hline \\ \\ PN3638 \\ \hline \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ $	0.8	1.1 2.0 20 10	V V
SMALL S C _{ob}	IGNAL CHARACTERISTICS Output Capacitance	$\begin{tabular}{lccccc} Ic = 50 & mA, I_B = 2.5 & mA \\ I_C = 300 & mA, I_B = 30 & mA \end{tabular}$ $\begin{tabular}{lcccc} $V_{CB} = 10 & V, f = 1.0 & MHz \\ P N3638 \\ P N3638A \end{tabular}$ $\begin{tabular}{lcccc} $V_{BE} = 0.5 & V, f = 1.0 & MHz \\ P N3638 \end{tabular}$	1.0	1.1 2.0 20 10 65	V V PF pF
SMALL S C _{ob}	IGNAL CHARACTERISTICS Output Capacitance Input Capacitance	$\label{eq:controller} \begin{array}{c} I_C = 50 \text{ mA}, \ I_B = 2.5 \text{ mA} \\ I_C = 300 \text{ mA}, \ I_B = 30 \text{ mA} \\ \end{array}$ $\begin{array}{c} V_{CB} = 10 \text{ V}, \ f = 1.0 \text{ MHz} \\ \begin{array}{c} \textbf{PN3638} \\ \textbf{PN3638A} \\ \end{array}$ $\begin{array}{c} V_{BE} = 0.5 \text{ V}, \ f = 1.0 \text{ MHz} \\ \begin{array}{c} \textbf{PN3638} \\ \textbf{PN3638A} \\ \end{array}$ $\begin{array}{c} I_C = 50 \text{ mA}, \ V_{CE} = 3.0 \text{ V}, \\ f = 100 \text{ MHz} \\ \begin{array}{c} \textbf{PN3638} \\ \textbf{PN3638A} \\ \end{array}$		1.1 2.0 20 10 65	V V PF pF
SMALL S C _{ob}	IGNAL CHARACTERISTICS Output Capacitance Input Capacitance	$\label{eq:controller} \begin{array}{c} I_C = 50 \text{ mA}, \ I_B = 2.5 \text{ mA} \\ I_C = 300 \text{ mA}, \ I_B = 30 \text{ mA} \\ \end{array}$ $\begin{array}{c} V_{CB} = 10 \text{ V}, \ f = 1.0 \text{ MHz} \\ \hline \textbf{PN3638} \\ \textbf{PN3638A} \\ \end{array}$ $\begin{array}{c} V_{BE} = 0.5 \text{ V}, \ f = 1.0 \text{ MHz} \\ \hline \textbf{PN3638} \\ \hline \textbf{PN3638A} \\ \\ I_C = 50 \text{ mA}, \ V_{CE} = 3.0 \text{ V}, \\ f = 100 \text{ MHz} \\ \hline \textbf{PN3638A} \\ \hline I_C = 10 \text{ mA}, \ V_{CE} = 10 \text{ V}, \\ \end{array}$	1.0 1.5	1.1 2.0 20 10 65	V V PF pF
SMALL S C _{ob}	IGNAL CHARACTERISTICS Output Capacitance Input Capacitance	$\label{eq:controller} \begin{array}{c} I_C = 50 \text{ mA}, \ I_B = 2.5 \text{ mA} \\ I_C = 300 \text{ mA}, \ I_B = 30 \text{ mA} \\ \end{array}$ $\begin{array}{c} V_{CB} = 10 \text{ V}, \ f = 1.0 \text{ MHz} \\ \begin{array}{c} \textbf{PN3638} \\ \textbf{PN3638A} \\ \end{array}$ $\begin{array}{c} V_{BE} = 0.5 \text{ V}, \ f = 1.0 \text{ MHz} \\ \begin{array}{c} \textbf{PN3638} \\ \textbf{PN3638A} \\ \end{array}$ $\begin{array}{c} I_C = 50 \text{ mA}, \ V_{CE} = 3.0 \text{ V}, \\ f = 100 \text{ MHz} \\ \begin{array}{c} \textbf{PN3638} \\ \textbf{PN3638A} \\ \end{array}$	1.0	1.1 2.0 20 10 65	V V PF pF
SMALL S Cob	IGNAL CHARACTERISTICS Output Capacitance Input Capacitance Small-Signal Current Gain Input Impedance	$\label{eq:controller} \begin{array}{c} I_C = 50 \text{ mA}, \ I_B = 2.5 \text{ mA} \\ I_C = 300 \text{ mA}, \ I_B = 30 \text{ mA} \\ \end{array}$ $\begin{array}{c} V_{CB} = 10 \text{ V}, \ f = 1.0 \text{ MHz} \\ & \text{PN3638} \\ & \text{PN3638A} \\ \end{array}$ $\begin{array}{c} V_{BE} = 0.5 \text{ V}, \ f = 1.0 \text{ MHz} \\ & \text{PN3638} \\ & \text{PN3638A} \\ \end{array}$ $\begin{array}{c} I_C = 50 \text{ mA}, \ V_{CE} = 3.0 \text{ V}, \\ f = 100 \text{ MHz} \\ & \text{PN3638A} \\ \end{array}$ $\begin{array}{c} I_C = 10 \text{ mA}, \ V_{CE} = 10 \text{ V}, \\ f = 1.0 \text{ kHz} \\ \end{array}$ $\begin{array}{c} I_C = 10 \text{ mA}, \ V_{CE} = 10 \text{ V}, \\ f = 1.0 \text{ kHz} \\ \end{array}$	1.0 1.5 25	1.1 2.0 20 10 65	V V PF pF
SMALL S Cob Cib	IGNAL CHARACTERISTICS Output Capacitance Input Capacitance Small-Signal Current Gain Input Impedance Output Admittance	$\label{eq:controller} \begin{array}{c} I_C = 50 \text{ mA}, \ I_B = 2.5 \text{ mA} \\ I_C = 300 \text{ mA}, \ I_B = 30 \text{ mA} \\ \end{array}$ $\begin{array}{c} V_{CB} = 10 \text{ V}, \ f = 1.0 \text{ MHz} \\ & \text{PN3638} \\ & \text{PN3638A} \\ \end{array}$ $\begin{array}{c} V_{BE} = 0.5 \text{ V}, \ f = 1.0 \text{ MHz} \\ & \text{PN3638} \\ & \text{PN3638A} \\ \end{array}$ $\begin{array}{c} I_C = 50 \text{ mA}, \ V_{CE} = 3.0 \text{ V}, \\ f = 100 \text{ MHz} \\ & \text{PN3638A} \\ I_C = 10 \text{ mA}, \ V_{CE} = 10 \text{ V}, \\ f = 1.0 \text{ kHz} \\ & \text{PN3638A} \\ \end{array}$ $\begin{array}{c} I_C = 10 \text{ mA}, \ V_{CE} = 10 \text{ V}, \\ f = 1.0 \text{ kHz} \\ \end{array}$	1.0 1.5 25	1.1 2.0 20 10 65 25	V V V pF pF pF pF
SMALL S	IGNAL CHARACTERISTICS Output Capacitance Input Capacitance Small-Signal Current Gain Input Impedance	$\begin{tabular}{lcccccccccccccccccccccccccccccccccccc$	1.0 1.5 25	20 10 65 25	V V V pF pF pF pF
SMALL S Cob Cib hfe hoe hre	IGNAL CHARACTERISTICS Output Capacitance Input Capacitance Small-Signal Current Gain Input Impedance Output Admittance Voltage Feedback Ratio	$\begin{tabular}{lllllllllllllllllllllllllllllllllll$	1.0 1.5 25	20 10 65 25 2.0 1.2 26	V V V pF pF pF pF
SMALL S Cob Cib hfe hie hoe hre	IGNAL CHARACTERISTICS Output Capacitance Input Capacitance Small-Signal Current Gain Input Impedance Output Admittance Voltage Feedback Ratio NG CHARACTERISTICS	$\begin{tabular}{lcccccccccccccccccccccccccccccccccccc$	1.0 1.5 25 100	20 10 65 25 2.0 1.2 26	V V V pF pF pF pF x10 ⁻⁴
SMALL S Cob Cib hfe hoe hre SWITCHI	IGNAL CHARACTERISTICS Output Capacitance Input Capacitance Small-Signal Current Gain Input Impedance Output Admittance Voltage Feedback Ratio NG CHARACTERISTICS Turn-on Time	$\begin{tabular}{lllllllllllllllllllllllllllllllllll$	1.0 1.5 25	20 10 65 25 2.0 1.2 26	V V V pF pF pF pF pF
SMALL S Cob Cib hfe hoe hre SWITCHI ton	IGNAL CHARACTERISTICS Output Capacitance Input Capacitance Small-Signal Current Gain Input Impedance Output Admittance Voltage Feedback Ratio NG CHARACTERISTICS	$\begin{tabular}{lcccccccccccccccccccccccccccccccccccc$	1.0 1.5 25 100	20 10 65 25 2.0 1.2 26	V V V pF pF pF pF x10 ⁻⁴
SMALL S Cob Cib hie hoe hre SWITCHI ton	IGNAL CHARACTERISTICS Output Capacitance Input Capacitance Small-Signal Current Gain Input Impedance Output Admittance Voltage Feedback Ratio NG CHARACTERISTICS Turn-on Time Delay Time	$\begin{split} &\text{Ic} = 50 \text{ mA, I}_{\text{B}} = 2.5 \text{ mA} \\ &\text{Ic} = 300 \text{ mA, I}_{\text{B}} = 30 \text{ mA} \\ \end{split}$ $&\text{V}_{\text{CB}} = 10 \text{ V, f} = 1.0 \text{ MHz} \\ &\text{PN3638} \\ &\text{PN3638A} \\ \end{split}$ $&\text{V}_{\text{BE}} = 0.5 \text{ V, f} = 1.0 \text{ MHz} \\ &\text{PN3638} \\ &\text{PN3638A} \\ \end{aligned}$ $&\text{Ic} = 50 \text{ mA, V}_{\text{CE}} = 3.0 \text{ V, f} = 100 \text{ MHz} \\ &\text{PN3638} \\ &\text{PN3638A} \\ \end{aligned}$ $&\text{Ic} = 10 \text{ mA, V}_{\text{CE}} = 10 \text{ V, f} = 1.0 \text{ kHz} \\ &\text{PN3638} \\ &\text{PN3638A} \\ \end{aligned}$ $&\text{Ic} = 10 \text{ mA, V}_{\text{CE}} = 10 \text{ V, f} = 1.0 \text{ kHz} \\ &\text{PN3638} \\ &\text{PN3638A} \\ \end{aligned}$ $&\text{V}_{\text{CC}} = 10 \text{ V, I}_{\text{C}} = 300 \text{ mA, I}_{\text{B1}} = 30 \text{ mA} \\ \end{aligned}$	1.0 1.5 25 100 75 20 70	20 10 65 25 2.0 1.2 26	V V V PF pF pF pF pF mhos x10 ⁻⁴ x10 ⁻⁴
SMALL S Cob Cib hfe hoe hre SWITCHI	IGNAL CHARACTERISTICS Output Capacitance Input Capacitance Small-Signal Current Gain Input Impedance Output Admittance Voltage Feedback Ratio NG CHARACTERISTICS Turn-on Time Delay Time Rise Time	$\begin{tabular}{lllllllllllllllllllllllllllllllllll$	1.0 1.5 25 100	20 10 65 25 2.0 1.2 26	V V V pF pF pF pF pF

TO-92 Tape and Reel Data FAIRCHILD SEMICONDUCTOR TM **TO-92 Packaging** Configuration: Figure 1.0 **TAPE and REEL OPTION** FSCINT Label sample See Fig 2.0 for various Reeling Styles CBVK//418019 **FSCINT** Label 5 Reels per Intermediate Box Customized F63TNR Label sample Label F63TNR LOT: CBVK741B019 QTY: 2000 FSID: PN222N Customized QTY1: QTY2: 375mm x 267mm x 375mm Intermediate Box TO-92 TNR/AMMO PACKING INFROMATION **AMMO PACK OPTION** See Fig 3.0 for 2 Ammo Packing Style Quantity EOL code **Pack Options** 2,000 D26Z Е 2,000 D27Z Ammo М 2,000 D74Z 2,000 D75Z **FSCINT** Unit weight = 0.22 gm Reel weight with components = 1.04 kg Ammo weight with components = 1.02 kg Max quantity per intermediate box = 10,000 units Label 5 Ammo boxes per Intermediate Box 327mm x 158mm x 135mm Immediate Box Customized F63TNR Customized Label Label 333mm x 231mm x 183mm Intermediate Box (TO-92) BULK PACKING INFORMATION **BULK OPTION** See Bulk Packing DESCRIPTION QUANTITY Information table J18Z TO-18 OPTION STD 2.0 K / BOX Anti-static Bubble Sheets TO-5 OPTION STD NO LEAD CLIP 1.5 K / BOX J05Z **FSCINT Label** NO EOL TO-92 STANDARD STRAIGHT FOR: PKG 92, NO LEADCLIP 2.0 K / BOX 94 (NON PROELECTRON SERIES), 96 TO-92 STANDARD STRAIGHT FOR: PKG 94 (PROELECTRON SERIES BCXXX, BFXXX, BSRXXX), 97, 98 L34Z NO LEADCLIP 2.0 K / BOX 2000 units per 114mm x 102mm x 51mm EO70 box for std option Immediate Box 5 EO70 boxes per intermediate Box 530mm x 130mm x 83mm Customized Intermediate box Label FSCINT Label 10,000 units maximum per intermediate box for std option

TO-92 Tape and Reel Data, continued

TO-92 Reeling Style Configuration: Figure 2.0

Machine Option "A" (H)



Style "A", D26Z, D70Z (s/h)

ADHESIVE TAPE IS ON BOTTOM SIDE FLAT OF TRANSISTOR IS ON BOTTOM

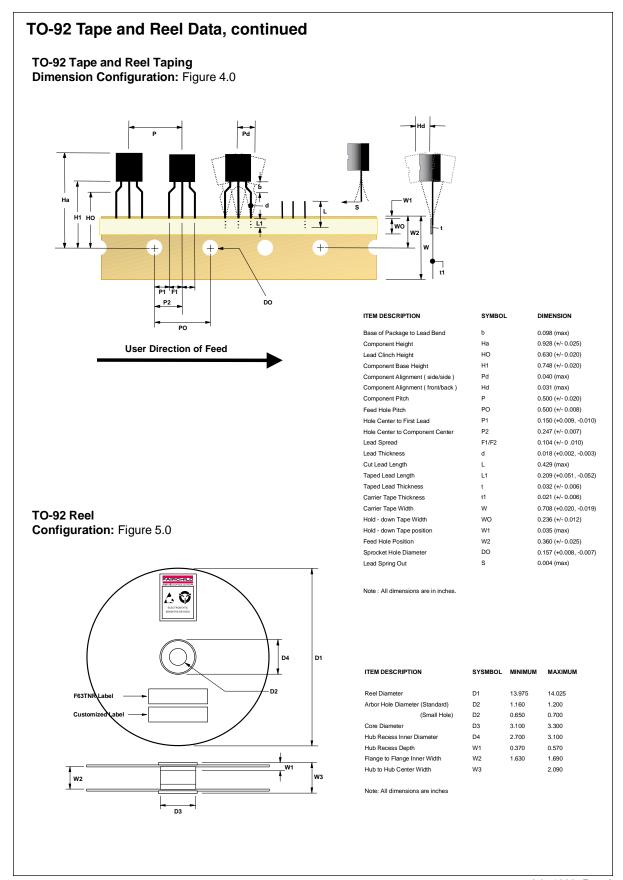
Machine Option "E" (J)

Style "E", D27Z, D71Z (s/h)

TO-92 Radial Ammo Packaging Configuration: Figure 3.0



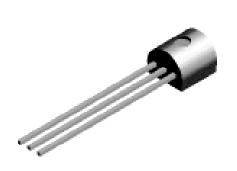


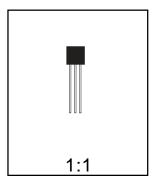


TO-92 Package Dimensions



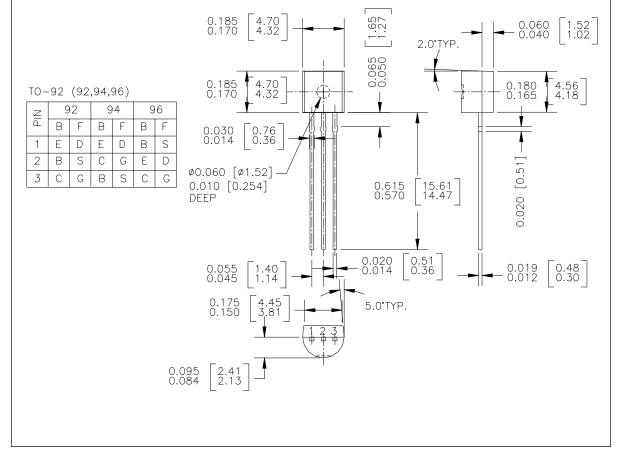
TO-92 (FS PKG Code 92, 94, 96)





Scale 1:1 on letter size paper
Dimensions shown below are in:
inches [millimeters]

Part Weight per unit (gram): 0.1977



TRADEMARKS

The following are registered and unregistered trademarks Fairchild Semiconductor owns or is authorized to use and is not intended to be an exhaustive list of all such trademarks.

 $ACEx^{TM}$ $FASTr^{TM}$ PowerTrench® SyncFETTM QFET™ TinyLogic™ Bottomless™ GlobalOptoisolator™ QSTM UHC™ CoolFET™ GTO™ QT Optoelectronics™ **VCXTM** CROSSVOLT™ HiSeC™

DOME™ ISOPLANAR™ Quiet Series™
E²CMOS™ MICROWIRF™ SILENT SWITC

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS.

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION. As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, or (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in significant injury to the user.

2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	This datasheet contains preliminary data, and supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
Obsolete	Not In Production	This datasheet contains specifications on a product that has been discontinued by Fairchild semiconductor. The datasheet is printed for reference information only.